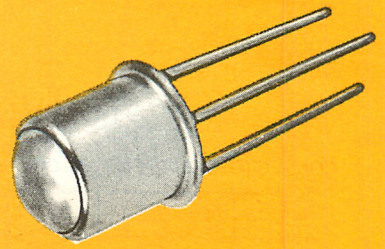


Product Data

CLT2130
CLT2140
CLT2150
CLT2160



Silicon Planar Epitaxial Phototransistors

GENERAL DESCRIPTION — The Clairex CLT2130, CLT2140, CLT2150, and CLT2160 are silicon NPN planar epitaxial phototransistors in a hermetically sealed TO-18 case with lens. The base lead is provided to enable more flexible circuit design. The units offer a full range of high current sensitivity for low illumination levels.

ABSOLUTE MAXIMUM RATINGS

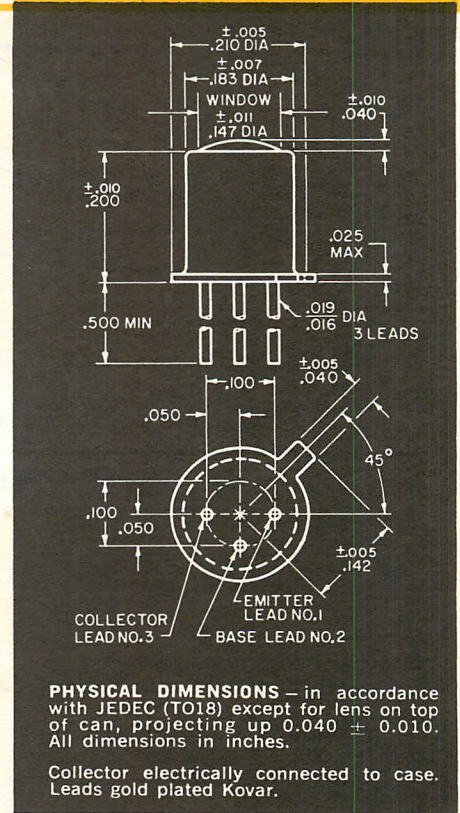
Maximum Temperatures
Storage Temperature -65°C to $+200^{\circ}\text{C}$
Operating Junction Temperature $+150^{\circ}\text{C}$

Maximum Power Dissipation
Total Dissipation
at 25°C Ambient Temperature $P_T = 250\text{mW}$ derate $2\text{mW}/^{\circ}\text{C}$
at 100°C Ambient Temperature $P_T = 100\text{mW}$

Maximum Voltages	CLT2130	CLT2140	CLT2150	CLT2160
V_{CBO} Collector to Base Voltage	80 volts	80 volts	80 volts	60 volts
V_{CEO} Collector to Emitter Voltage	50 volts	40 volts	40 volts	30 volts
V_{ECO} Emitter to Collector Voltage	5 volts	5 volts	5 volts	5 volts

Maximum Current
 I_C Collector Current 200ma

ELECTRICAL CHARACTERISTICS (25°C Free Air unless otherwise designated.)



Symbol	Characteristics	Test Conditions	CLT2130		CLT2140		CLT2150		CLT2160		Unit
			Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
$I_L (I_{CEO})$	Light Current	$V_{CE} = 5\text{V}, H = 5\text{mW}/\text{cm}^2$, Note 1	0.6	1.8	1.2	3.6	2.4	7.2	4.0	12.0	ma
$I_D (I_{CEO})$	Dark Current	$V_{CE} = 10\text{ volts}, H = 0$		25		25		25		25	na
$I_D (I_{CEO})$	Dark Current	$V_{CE} = 10\text{ volts}, H = 0, T = +100^{\circ}\text{C}$		25		25		25		25	μa
BV_{CEO}	Collector to Emitter Breakdown Voltage	$I_C = .1\text{ma}$	50		40		40		30		volts
BV_{CBO}	Collector to Base Breakdown Voltage	$I_C = .1\text{ma}$	80		80		80		60		volts
BV_{ECO}	Emitter to Collector Breakdown Voltage	$I_{EC} = .1\text{ma}$	5		5		5		5		volts
t_r	Light Current Rise Time (unsaturated)	$R_L = 100\Omega$ $V_{CC} = +5.0\text{ volts}$	3 Typical		3 Typical		3 Typical		3 Typical		μsec
t_f	Light Current Fall Time (unsaturated)	Note 2	3 Typical		3 Typical		3 Typical		3 Typical		μsec
$V_{CE (SAT)}$	Collector to Emitter Saturation Voltage	$I_C = 10\text{ma}, I_B = 0.5\text{ma}$ $H = 0$		0.35		0.30		0.30		0.30	volts

Note 1: The light source is a frosted tungsten incandescent lamp at 2854°K .

Note 2: The light source is a gallium arsenide LED pulsed with a rise and fall time of $< 0.3\ \mu\text{sec}$.



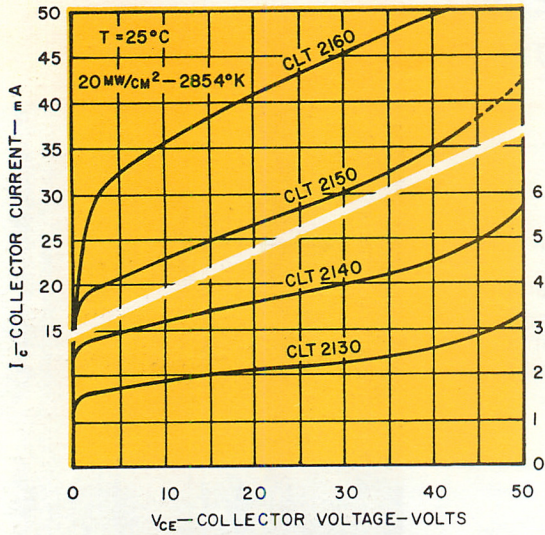
CLAIREX ELECTRONICS

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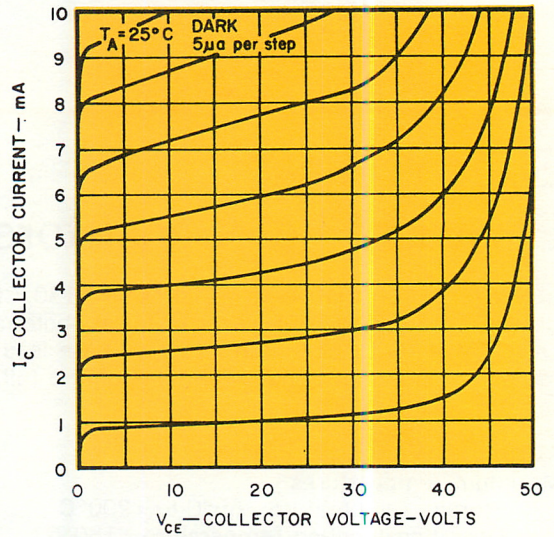
560 South Third Avenue, Mount Vernon, N.Y. 10550 · (914) 664-6602

Typical Electrical Characteristics

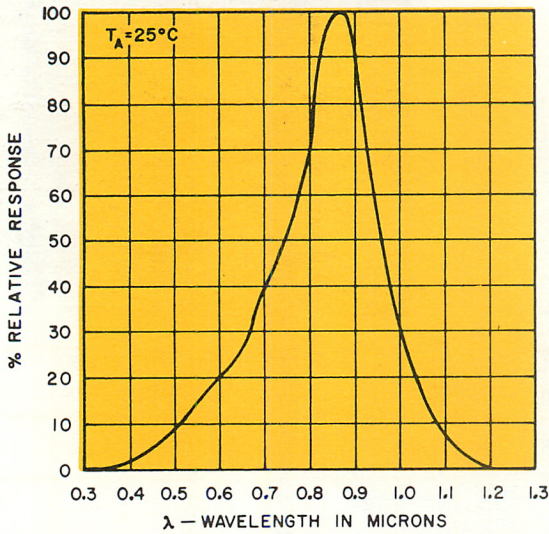
COLLECTOR CURRENT vs. COLLECTOR VOLTAGE



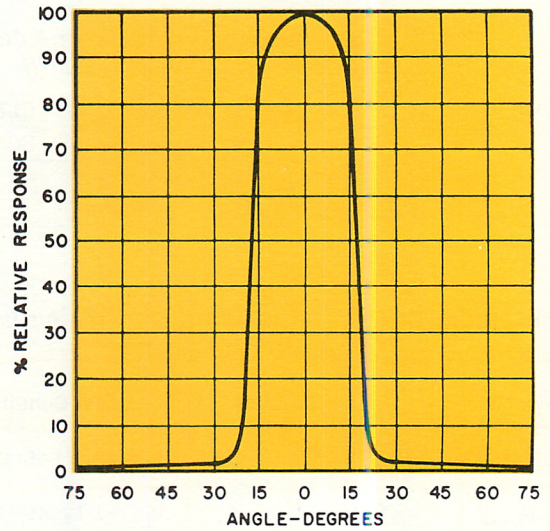
COLLECTOR CHARACTERISTICS CLT 2150



SPECTRAL RESPONSE



ANGULAR RESPONSE



LIGHT CURRENT vs. IRRADIATION

